

# **High Performance Synchronous Rectifier**

### **Features**

- Secondary side synchronous rectifier controller, built-in 40V~120V Power MOSFET, output voltage range 3.3V~20V
- Support CCM, QR, and DCM working mode
- Accurate secondary side detection
- Support constant voltage/constant current operation
- Unique VCC self-supply technology
- VCC power supply under-voltage protection
- VCC over-voltage clamp
- Support maximum frequency of ~ 160 KHz
- TSR detection time 25ns (typical value)
- Small number of peripheral components, for low-cost solution
- SOP-8 package

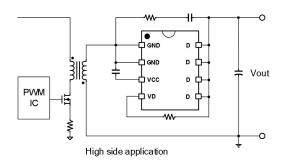
## Description

GR9383 is a high-performance secondary side synchronous rectifier control chip and supports CCM, QR, DCM and other working modes, with special VCC self-power supply mode, it does not need one more winding for power supply, reduce peripheral components and design cost. GR9383 integrates VCC under-voltage protection, over-voltage clamp, and drive pin deinterference technology.

## **Applications**

- Mobile phone charger
- AC/DC adapter

## **Typical Application Information**



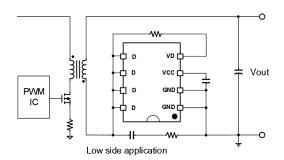
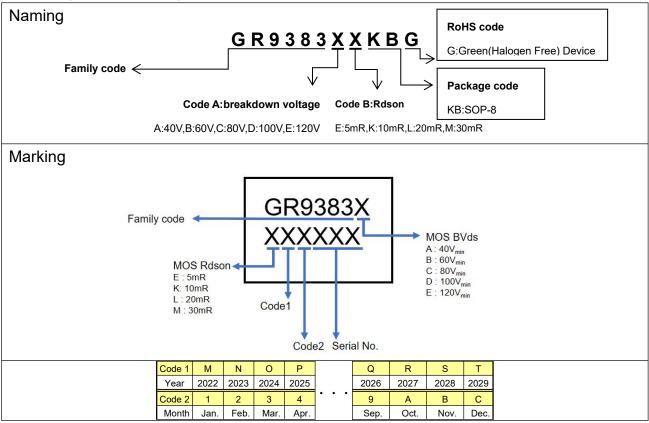


Figure 1 Application CKT of synchronous rectifier chip



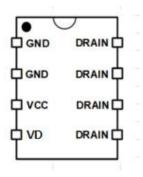
Ordering and Marking Information



Nanjing Greenchip Semicondutor Co., Ltd.reserves the right to make changes to improve reliability or manufacture ability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

# Pin Configuration

### SOP-8



### Pin Description

### SOP-8

Pin No.	Name	Function			
1,2	GND	Ground pin			
3	VCC	Power supply pin			
4	VD	MOSFET Drain Voltage Sense			
5,6,7,8	DRAIN	Drain of built-in power MOSFET			



## **Absolute Maximum Ratings**

Drain Voltage	note 2)
VCC power supply voltage	).3~7V
Maximum working interface temperature	150℃
Storage temperature range	150℃
Lead temperature (SOP-8, tin soldering, 10 sec)	<b>230</b> ℃
Lead temperature (all lead-free PKG,tin soldering, 10 sec)	260℃
ESD, voltage protection, machine mode	300V
ESD, voltage protection, human model	3KV

Note 1: If the component stress exceeds the listed absolute maximum rating (Absolute Maximum Ratings), it may cause permanent damage and safety will not be guaranteed. Not only the stress ratings, the component functions operate in these or any other circumstances, and the operating parts beyond the electrical specification are not included. Long time operation affects the reliability of the product.

Note 2: According to the voltage specification of the built-in power MOSFET, the product code voltage specification is described in the specification column.

## **Recommended Operating Conditions**

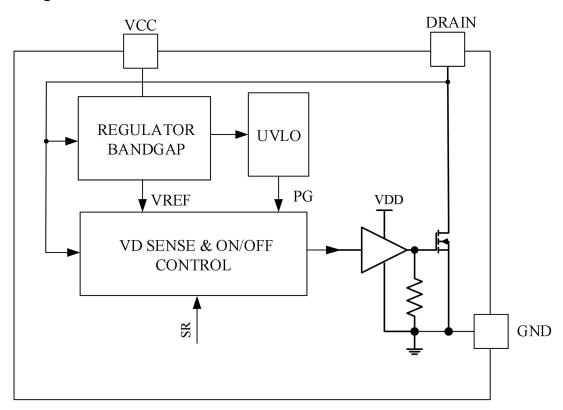
Item	minimum	maximum	unit
The surface temperature	-40	125	°C
Ambient temperature	-40	85	$^{\circ}$
Power supply voltage	4	6	V
VCC capacity	0.1	1	μF

#### Notes:

- Do not exceed the IC maximum absolute surface temperature, which is related to the IC operating power and the IC package thermal resistance.
- Put the small signal components as close to the IC pin as possible
- For VCC power supply capacitors, recommend using SMD ceramic capacitors



# Block Diagram





## Electrical Characteristics (TA = +25°C unless otherwise stated, VCC = 5.0V)

parameter		Min.	Тур.	Max.	unit
SUPPLY VOLTAGE (VCC Pin)					
VCC working voltage	VCC	4.7	5	5.3	V
Start-up voltage UVLO-ON	UVLO_on	3.4	3.6	3.8	V
Turn-off voltage UVLO-OFF	UVLO_off	2.8	3.1	3.3	V
start-up current	Ist			100	uA
quiescent current	lvcc_st		180	300	uA
VD					
SR _ ON threshold voltage	SR <sub>ON</sub>		-100		mV
SR _ REG threshold voltage	SR <sub>OFF2</sub>	-50	-30	-15	mV
SR _ OFF threshold voltage	SR <sub>OFF</sub>		0		mV
TSR detection time (VD drop 2V~ -100 mV)			25		ns
Minimum on Time	Ton <sub>min</sub>	450	600	750	ns
SR turn on delay	TD_ON		25	50	ns
SR turnoff delay	TD_OFF		15	50	ns
MOSFET		ı	•	<u> </u>	
GR9383AK Note1.					
Power MOSFET Rdson	RDSON		10.5	15	mΩ
Power MOSFET breakdown voltage	BV	40			V
GR9383BK					
Power MOSFET Rdson	RDSON		10.5	15	mΩ
Power MOSFET breakdown voltage	BV	60			V
GR9383BE					
Power MOSFET Rdson	RDSON		7.0	8.5	mΩ
Power MOSFET breakdown voltage	BV	60			V
GR9383CE		<b>.</b>	,	,	
Power MOSFET Rdson	RDSON		5	7.5	mΩ
Power MOSFET breakdown voltage	BV	80			V
GR9383DE		1	,	1	
Power MOSFET Rdson	RDSON		5.5	8.2	mΩ
Power MOSFET breakdown voltage	BV	100			V
GR9383DK		1	,	1	
Power MOSFET Rdson	RDSON		9	12	mΩ
Power MOSFET breakdown voltage	BV	100			V
GR9383EK					
Power MOSFET Rdson	RDSON		10.5	15	mΩ
Power MOSFET breakdown voltage	BV	120			V



Note1: product model suffix code GR9383XX: the first code X is to define the Power MOSFET breakdown voltage, the second code X is to define the Power MOSFET Rdson.

Only several representative products are listed in the table above, and the different MOS specifications are defined in the table below.

MOSFET specification sheet:

Product model suffix code-first code	Power MOSFET breakdown voltage	Product code suffix code-second code	Power MOSFET Rdson
А	40-50	F	Rdson <5 mohm
В	60	Е	Rdson 5-10 mohm
С	80	К	Rdson 10-20 mohm
D	100	L	Rdson 20-30 mohm
E	120	M	Rdson 30-40 mohm
F	150		

## **Application Information**

#### **Preface**

GR9383 is a high performance synchronous rectification control chip applied to the switching mode power supply, this chip can replace the short diode in the converter, in order to improve the conversion efficiency, GR9383 supports CCM, QR, and DCM working mode, self-supply function of VCC pin do not need the third winding for power supply and reduce the peripheral components and design cost.

The built-in Power MOSFET has different breakdown voltages such as 40V / 60V / 80V / 100V / 120V, which can be used in different output voltages.

### VCC supply

VCC is the output pin of the self-supplied regulator, and the power supply can be stabilized by 0.1 uF ~ 1 uF capacitor filter on the VCC pin to GND. This regulator will supply the current through the internal SR MOSFET Drain of the chip.

At the same time, the VCC has undervoltage

locking, with the on voltage of 3.6V and the off voltage of 3.1V. The hysteresis voltage is 0.5V to avoid abnormal on and off during the startup process.

### Synchronous rectifier is turned on

GR9383 uses the VDS voltage on SR MOS to control and judge on and off. As shown in Figure 2, when the time of SR MOS VDS dropping from 2V to SR open threshold voltage-100mV is less than the internal setting time of the chip, after 25ns of delay time, SR MOS will be turned on.

### Synchronous rectifier off

When SR MOS is turned on, the VDS voltage of SR MOS will gradually rise as the continuous current on the secondary side gradually decreases. When the GR9383 detects that the VDS voltage reaches the SR off threshold voltage of 0 mV, the SR MOS will be turned off after 15ns of delay time.

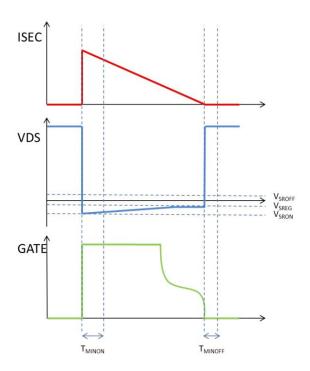
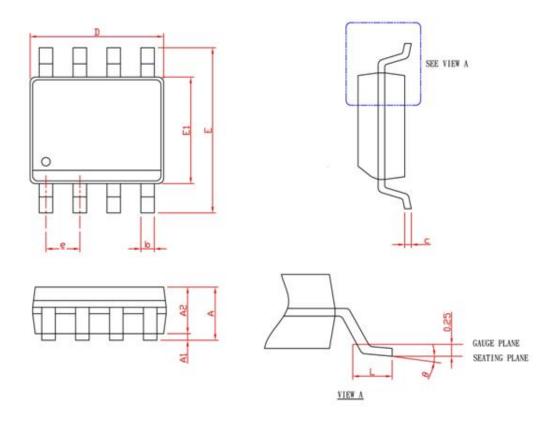


Figure 2On and off time sequence of the chip



# Package Information



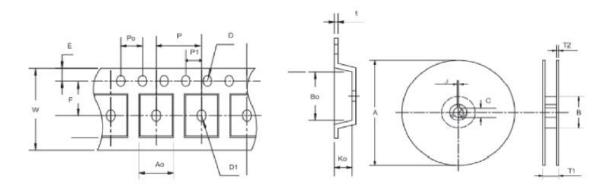
	SOP-8				
SYMBOL	MILLIMETERS				
	MIN.	MAX.			
Α		1.75			
A1	0.10	0.25			
A2	1.25				
b	0.31	0.51			
С	0.10	0.25			
D	4.70	5.10			
E	5.80	6.20			
E1	3.70	4.10			
е	1.27	BSC			
L	0.40	1.27			
θ	0°	8°			

### Notes:

- 1. Followed from JEDEC MS-012 AA.
- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "E" does not include inner-lead flash or protrusions. Inner-lead flash and protrusions shall not exceed 10mil per side.



# Carrier Tape & Reel Dimensions



PKG TYPE	W	E	F	P0	A0	Р	P1	В0	K0	Α	В	T1
SOP8	12+0.3	1.75+0.1	5.5+0.05	4+0.1	6.4+0.2	8+0.1	2+0.2	5.2+0.2	2.1+0.2	330+2	50min	12.4+2/-0

(mm)

## **Devices Per Unit**

<b>Application</b>	Carrier Width	Cover Tape Width	Devices Per Reel		
SOP8	12	-	2500		



## Feed direction

## SOP-8

